

Fig. 1

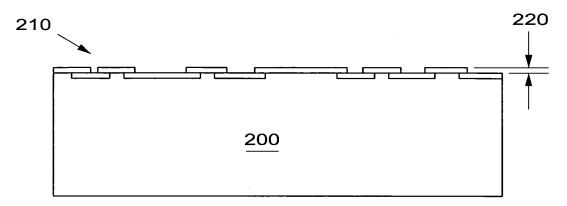


Fig. 2a

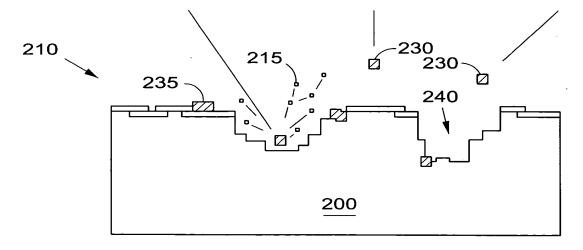


Fig. 2b

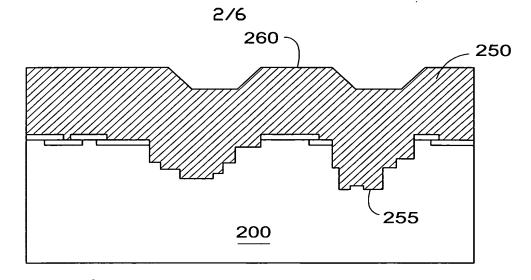


Fig. 2c

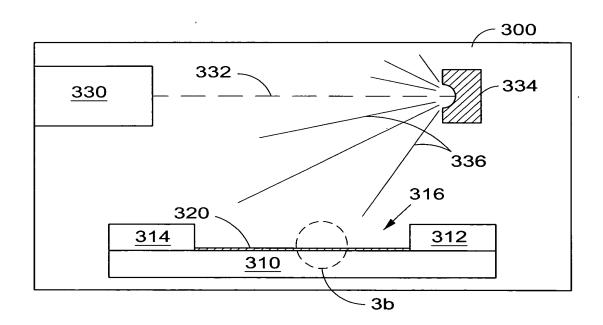


Fig. 3a

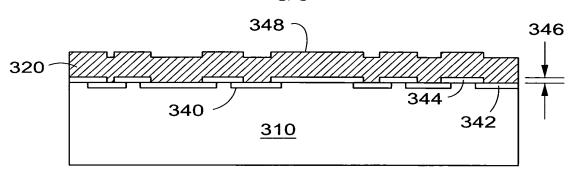
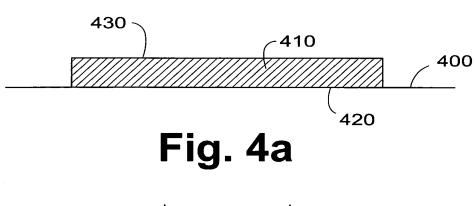


Fig. 3b



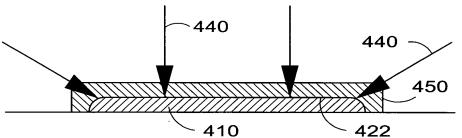


Fig. 4b

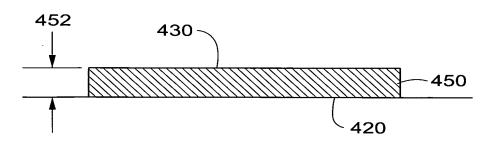


Fig. 4c

TITLE: LOW-TEMPERATURE GROWN HIGH-QUALITY ULTRA-THIN PRASEODYMIUM GATE DIELECTRICS INVENTORS NAME: Kie Y. Ahn et al.

Dkt #: 1303.033US2

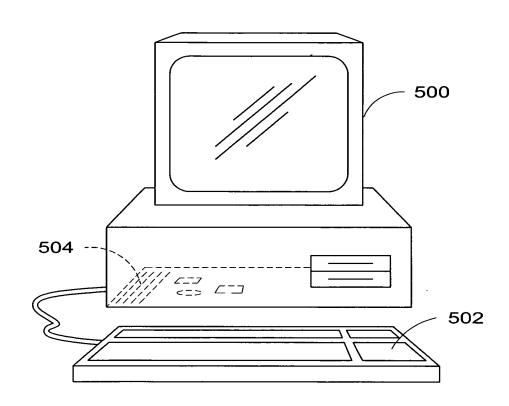


Fig. 5

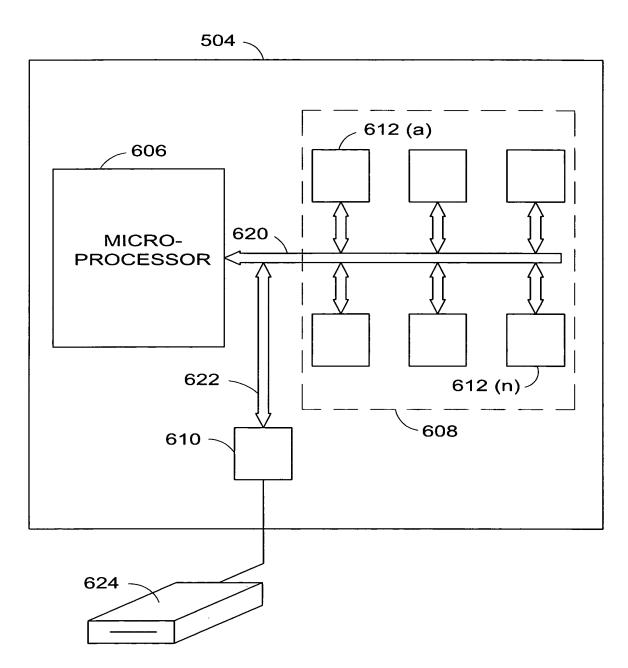


Fig. 6

